N-Channel Power MOSFET 600 V, 4.8 Ω

Features

- Low ON Resistance
- Low Gate Charge
- ESD Diode–Protected Gate
- 100% Avalanche Tested
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



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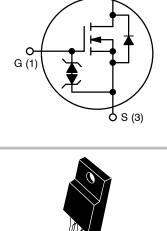
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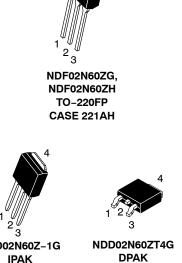
V _{DSS}	R _{DS(on)} (MAX) @ 1 A
600 V	4.8 Ω

N-Channel D (2)

Rating	Symbol	NDF	NDD	Unit
Drain-to-Source Voltage	V _{DSS}	600		V
Continuous Drain Current $R_{\theta JC}$ (Note 1)	۱ _D	2.4	2.2	A
Continuous Drain Current $R_{\theta JC}$ T _A = 100°C (Note 1)	۱ _D	1.6	1.4	A
Pulsed Drain Current, V _{GS} @ 10 V	I _{DM}	10	9	Α
Power Dissipation $R_{\theta JC}$	PD	24	57	W
Gate-to-Source Voltage	V _{GS}	±3	0	V
Single Pulse Avalanche Energy, $I_D = 2.4 A$	E _{AS}	12	0	mJ
ESD (HBM) (JESD 22–A114)	V _{esd}	2500		V
RMS Isolation Voltage (t = 0.3 sec., R.H. \leq 30%, T _A = 25°C) (Figure 17)	V _{ISO}	4500		V
Peak Diode Recovery (Note 2)	dv/dt	4.5		V/ns
Continuous Source Current (Body Diode)	I _S	2.4		A
Maximum Temperature for Soldering Leads	ΤL	260		°C
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 tc	150	°C

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)





NDD02N60Z-1G IPAK CASE 369D

CASE 369AA

ORDERING AND MARKING INFORMATION

See detailed ordering, marking and shipping information on page 7 of this data sheet.

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assumed, damage may occur and reliability may be affected.

2. $I_{SD} = 2.4$ Å, di/dt ≤ 100 Å/ μ s, $V_{DD} \leq BV_{DSS}$, $T_J = +150^{\circ}C$

1. Limited by maximum junction temperature

THERMAL RESISTANCE

Parameter			Value	Unit
Junction-to-Case (Drain)	NDF02N60Z NDD02N60Z	$R_{\theta JC}$	4.9 2.2	°C/W
Junction-to-Ambient Steady State	(Note 3) NDF02N60Z (Note 4) NDD02N60Z (Note 3) NDD02N60Z-1	$R_{ heta JA}$	51 41 80	

3. Insertion mounted

4. Surface mounted on FR4 board using 1" sq. pad size, (Cu area = 1.127 in sq [2 oz] including traces).

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

Characteristic	Test Conditions		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V_{GS} = 0 V, I_D = 1 mA		BV _{DSS}	600			V
Breakdown Voltage Temperature Coeffi- cient	Reference to 25°C I _D = 1 mA	Э,	$\Delta BV_{DSS}/\Delta T_{J}$		0.6		V/°C
Drain-to-Source Leakage Current	<u> </u>	25°C	I _{DSS}			1	μΑ
	$V_{DS} = 600 \text{ V}, V_{GS} = 0 \text{ V}$	150°C				50	
Gate-to-Source Forward Leakage	V _{GS} = ±20 V		I _{GSS}			±10	μΑ
ON CHARACTERISTICS (Note 5)							
Static Drain-to-Source On-Resistance	V _{GS} = 10 V, I _D = 1.0	A (R _{DS(on)}		4.0	4.8	Ω
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 50$	μA	V _{GS(th)}	3.0	4.0	4.5	V
Forward Transconductance	V _{DS} = 15 V, I _D = 1.2	2 A	g fs		1.7		S
DYNAMIC CHARACTERISTICS							
Input Capacitance (Note 6)	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		C _{iss}	215	274	325	pF
Output Capacitance (Note 6)			C _{oss}	25	34	45	
Reverse Transfer Capacitance (Note 6)			C _{rss}	4.0	7.0	10	
Total Gate Charge (Note 6)			Qg	5.0	10	16	nC
Gate-to-Source Charge (Note 6)	V _{DD} = 300 V, I _D = 2.	4 A,	Q _{gs}	1.5	2.4	4.0	1
Gate-to-Drain ("Miller") Charge (Note 6)	V _{GS} = 10 V		Q _{gd}	3.5	5.3	8.0	
Plateau Voltage			V _{GP}		6.4		V
Gate Resistance			R _g		4.9		Ω
RESISTIVE SWITCHING CHARACTERIST	ICS				•	•	
Turn-On Delay Time			t _{d(on)}		9.0		ns
Rise Time	V _{DD} = 300 V, I _D = 2.	4 A,	t _r		7.0		1
Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{G} = 5 \Omega$		t _{d(off)}		15		1
Fall Time			t _f		7.0		
SOURCE-DRAIN DIODE CHARACTERIS	TICS (T _C = 25°C unless other	erwise not	ed)				
Diode Forward Voltage	I _S = 2.4 A, V _{GS} = 0		V _{SD}			1.6	V

 V_{GS} = 0 V, V_{DD} = 30 V I_S = 2.4 A, di/dt = 100 A/ μs Q_{rr} Reverse Recovery Charge 0.7 μC Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

t_{rr}

240

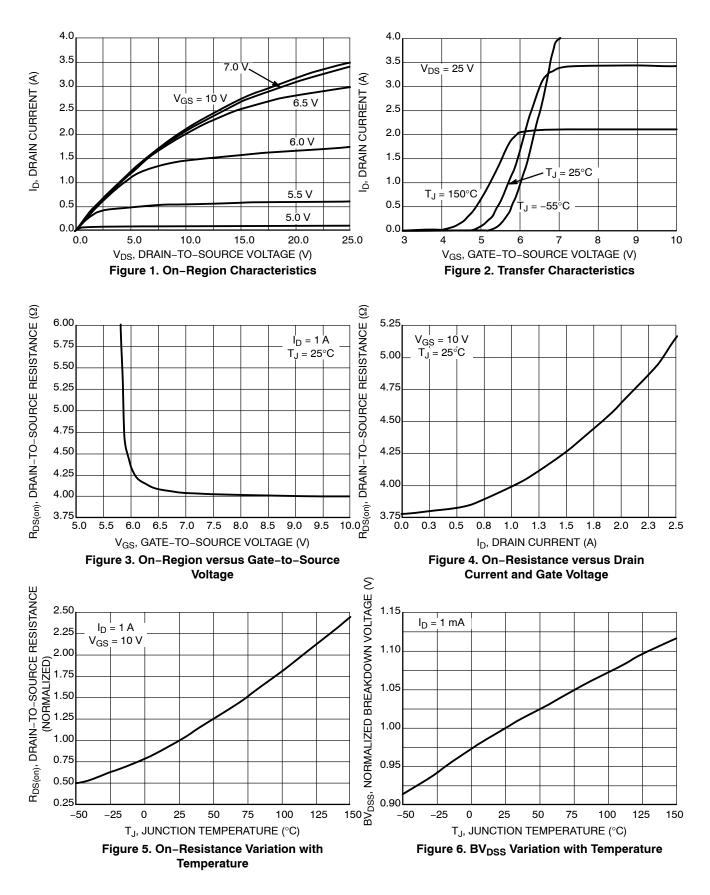
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performance may not be indicated by the Electrical Characteristics if operated under different conditions.

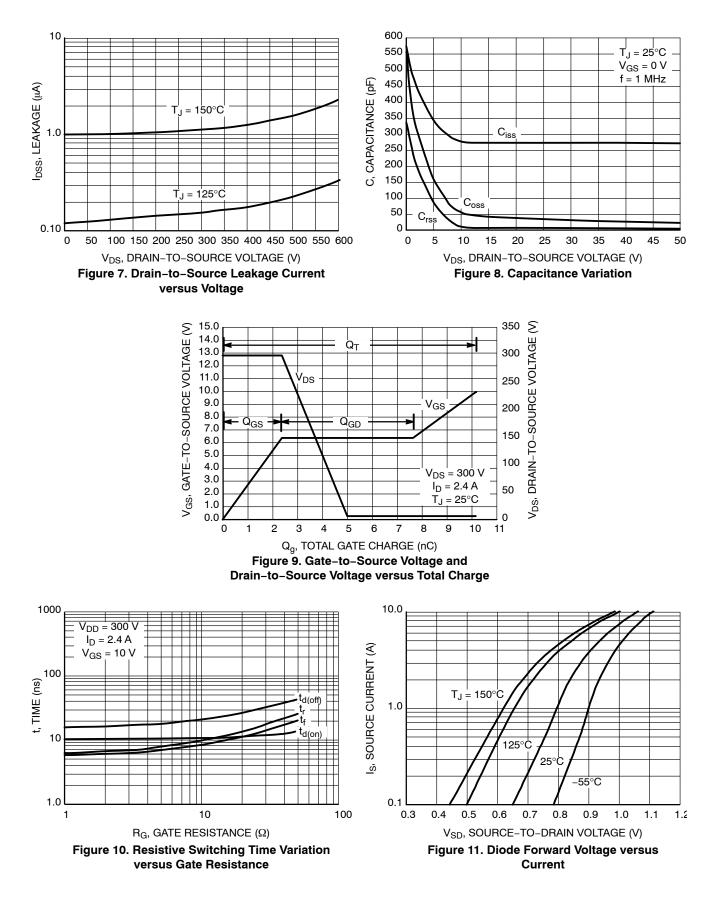
5. Pulse Width \leq 380 µs, Duty Cycle \leq 2%. 6. Guaranteed by design.

Reverse Recovery Time

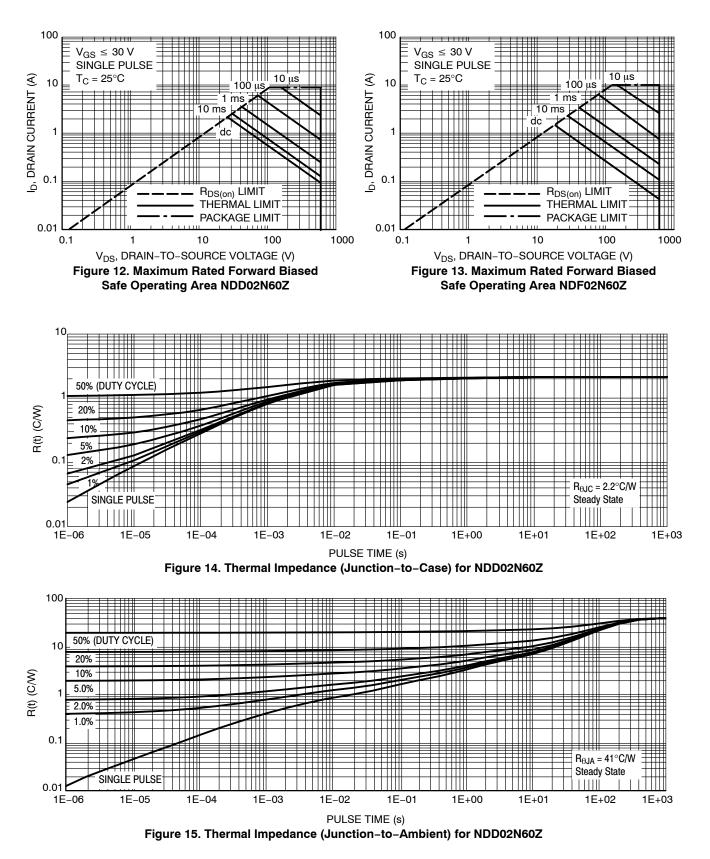
TYPICAL CHARACTERISTICS

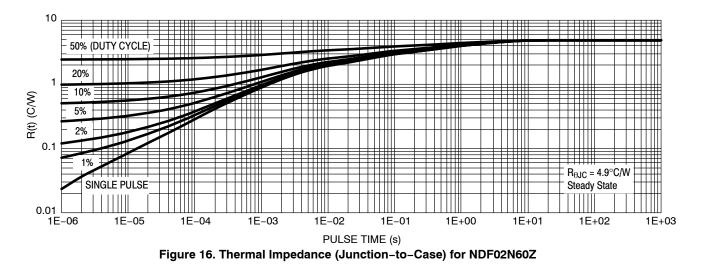


TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS





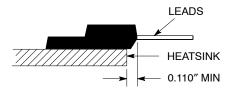


Figure 17. Isolation Test Diagram

Measurement made between leads and heatsink with all leads shorted together.

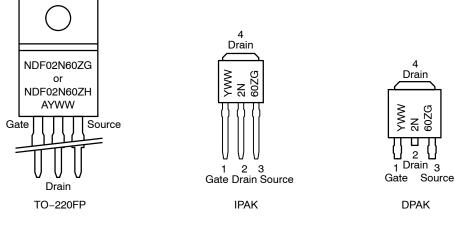
*For additional mounting information, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ORDERING INFORMATION

Order Number	Package	Shipping [†]
NDF02N60ZG	TO-220FP (Pb-Free, Halogen-Free)	50 Units / Rail
NDF02N60ZH	TO-220FP (Pb-Free, Halogen-Free)	50 Units / Rail
NDD02N60Z-1G	IPAK (Pb-Free, Halogen-Free)	75 Units / Rail
NDD02N60ZT4G	DPAK (Pb-Free, Halogen-Free)	2500 / Tape and Reel

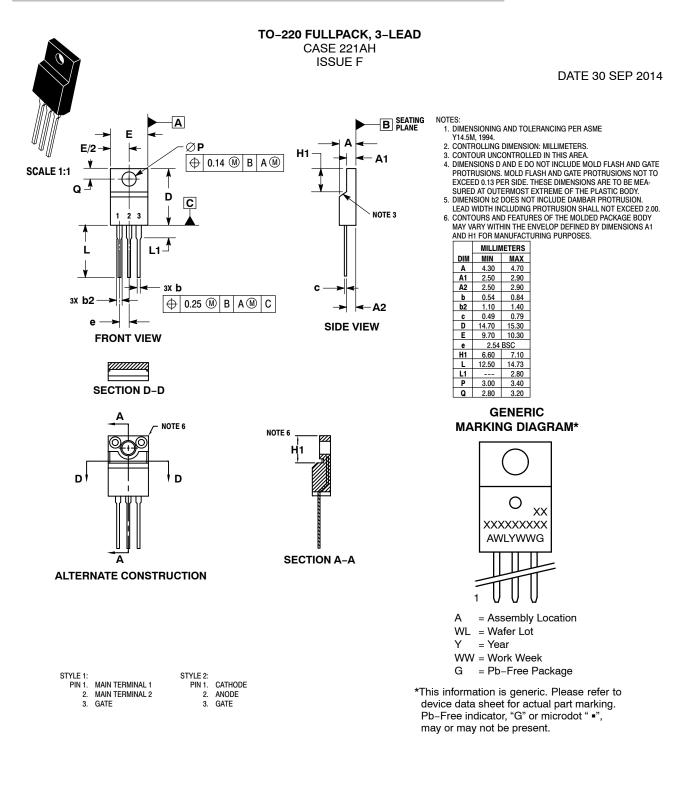
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS



- A = Location Code
- Y = Year
- WW = Work Week
- G, H = Pb-Free, Halogen-Free Package

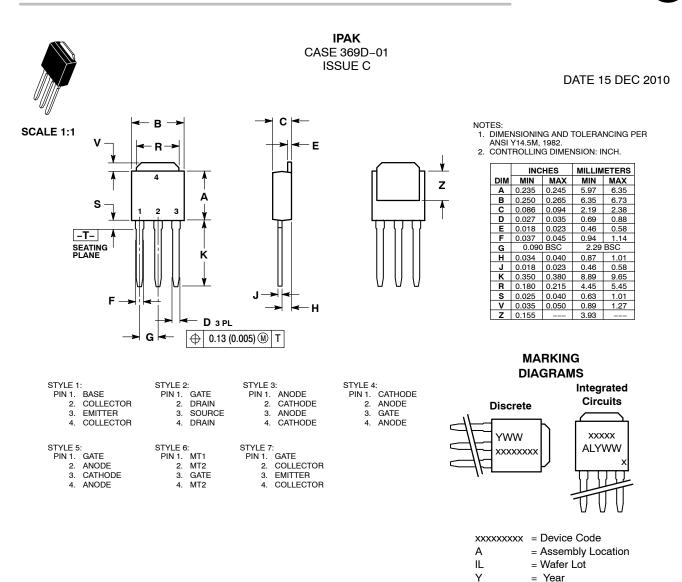




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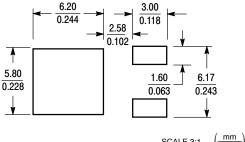
= Work Week

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1

L3

L4



*For additional information on our Pb-Free strategy and soldering

SCALE 3:1

Inches

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 03 JUN 2010

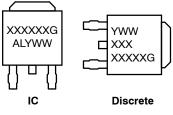
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- 2. CONTROLLING DIMENSION: INCHES. 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-
- THERMAL FAD CONTOR OF FIGURE WITHIN DEMONSIONS b3, L3 and Z.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL
- NOT EXCEED 0.006 INCHES PER SIDE 5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM

	INC	HES	MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
q	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
Е	0.250	0.265	6.35	6.73
е	0.090	BSC	2.29 BSC	
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108	REF	EF 2.74 REF	
L2	0.020	0.020 BSC		BSC
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Ζ	0.155		3.93	

MARKING DIAGRAM*



= Device Code = Assembly Location L = Wafer Lot Y = Year = Work Week WW G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking.

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